COMPLIANT



Vishay High Power Products

Passivated Assembled Circuit Elements, 40 A



PACE-PAK (D-19)

PRODUCT SUMMARY	
Io	40 A

FEATURES

- · Glass passivated junctions for greater reliability
- · Electrically isolated base plate
- Available up to 1200 V_{RRM}/V_{DRM}
- High dynamic characteristics
- Wide choice of circuit configurations
- Simplified mechanical design and assembly
- UL E78996 approved
- Compliant to RoHS directive 2002/95/EC

DESCRIPTION

The P400 series of integrated power circuits consists of power thyristors and power diodes configured in a single package. With its isolating base plate, mechanical designs are greatly simplified giving advantages of cost reduction and reduced size.

Applications include power supplies, control circuits and battery chargers.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
lo	80 °C	40	А		
I _{TSM} ,	50 Hz	385	A		
I _{FSM}	60 Hz	400	А		
l ² t	50 Hz	745	- A ² s		
1-1	60 Hz	680			
$I^2\sqrt{t}$		7450	A ² √s		
V _{RRM}	Range	400 to 1200	V		
V _{ISOL}		2500	V		
T _J		40 to 105	°C		
T _{Stg}		- 40 to 125			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
V _{RRM} /V _{DRM} , MAXIMUM TYPE REPETITIVE PEAK REVERSE AND NUMBER PEAK OFF-STATE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J MAXIMUM mA		
P401, P421, P431	400	500			
P402, P422, P432	600	700			
P403, P423, P433	800	900	10		
P404, P424, P434	1000	1100			
P405, P425, P435	1200	1300			

P400 Series

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ON-STATE CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum DC output current		Full bridge circuits		40	Α	
at case temperature	I _O	ruii briage	Circuits		80	°C
		t = 10 ms	No voltage		385	
Maximum peak, one-cycle non-repetitive on-state or	I _{TSM} ,	t = 8.3 ms	reapplied		400	
forward current	I _{FSM}	t = 10 ms	100 % V _{RRM}		325	A
		t = 8.3 ms	reapplied	Sinusoidal half wave,	340	•
		t = 10 ms	No voltage	initial $T_J = T_J$ maximum	745	A ² s
Maximum 12t fau funing	l ² t	t = 8.3 ms	reapplied		680	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		530	
		t = 8.3 ms	reapplied		480	
Maximum I ² √t for fusing	l²√t	$t=0.1$ ms to 10 ms, no voltage reapplied l^2t for time $tx=l^2 \sqrt{t} \cdot \sqrt{t}x$		7450	A²√s	
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum		0.83	V	
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		1.03	V	
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $T_J = T_J$ maximum		9.61	0
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		7.01	mΩ	
Maximum on-state voltage drop	V_{TM}	$I_{TM} = \pi \times I_{T(AV)}$		4.4	V	
Maximum forward voltage drop	V_{FM}	$I_{FM} = \pi \times I_{F(AV)}$ $T_J = 25 \text{ °C}$		1.4	V	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	$T_J = 125 ^{\circ}\text{C}$ from 0.67 V_{DRM} $I_{TM} = \pi \times I_{T(AV)}, I_g = 500 \text{mA}, t_r < 0.5 \mu\text{s}, t_p > 6 \mu\text{s}$		200	A/μs	
Maximum holding current	I _H			130	mA	
Maximum latching current	ΙL	T _J = 25 °C anode supply = 6 V, resistive load		250	IIIA	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = 125 °C, exponential to 0.67 V _{DRM} gate open	200	V/µs
Maximum peak reverse and off-state leakage current at V _{RRM} , V _{DRM}	I _{RRM} , I _{DRM}	T _J = 125 °C, gate open circuit	10	mA
Maximum peak reverse leakage current	I _{RRM}	T _J = 25 °C	100	μΑ
RMS isolation voltage	V _{ISOL}	50 Hz, circuit to base, all terminals shorted, $T_J = 25 ^{\circ}\text{C}$, $t = 1 \text{s}$	2500	V

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TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P _{GM}			8	W
Maximum average gate power	P _{G(AV)}			2] vv
Maximum peak gate current	I _{GM}			2	Α
Maximum peak negative gate voltage	-V _{GM}			10	V
Maximum gate voltage required to trigger	V _{GT}	T _J = - 40 °C	Anode supply =	3	
		T _J = 25 °C		2	V
		T _J = 125 °C		1	1
		T _J = - 40 °C		90	
Maximum gate current required to trigger	I _{GT}	T _J = 25 °C		60	mA
		T _J = 125 °C		35	1
Maximum gate voltage that will not trigger	V_{GD}	$T_J = 125 ^{\circ}\text{C}$, rated V_{DRM} applied 0.2		0.2	V
Maximum gate current that will not trigger	I_{GD}			mA	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case per junction	R _{thJC}	DC operation	1.05	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.10	\ \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
Mounting torque, base to heatsink (1)			4	Nm
Approximate weight			58	g
Approximate weight			2.0	OZ.

Note

⁽¹⁾ A mounting compund is recommended and the torque should be checked after a period of 3 hours to allow for the spread of the compound

CIRCUIT TYPE AND CODING (1)							
	CIRCUIT "0"	CIRCUIT "2"	CIRCUIT "3"				
Terminal positions	AC1 G1 - AC2 G2 +	AC1 G1 - AC2 G2 +	AC2 G2 - 				
Schematic diagram	AC20 G2 (+)	G1 9 9 G2 AC20 AC10 (-) (+)	G3 , G1 AC1 AC2, G4 G2 (+)				
	Single phase hybrid bridge common cathode	Single phase hybrid bridge doubler	Single phase all SCR bridge				
Basic series	P40.	P42.	P43.				
With voltage suppression	P40.K	P42.K	P43.K				
With freewheeling diode	P40.W	-	-				
With both voltage suppression and freewheeling diode	P40.KW	-	-				

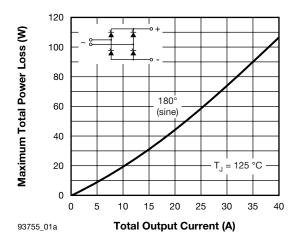
Note

 $^{^{(1)}}$ To complete code refer to Voltage Ratings table, i.e.: For 600 V P40.W complete code is P402W

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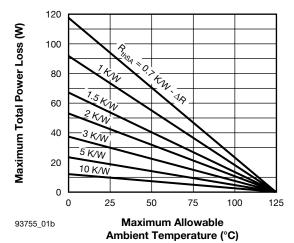


Fig. 1 - Current Ratings Nomogram (1 Module Per Heatsink)

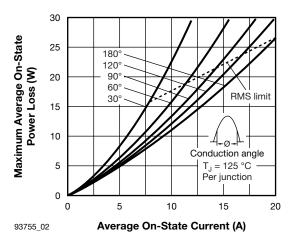


Fig. 2 - On-State Power Loss Characteristics

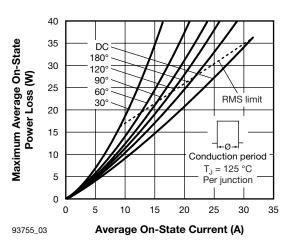


Fig. 3 - On-State Power Loss Characteristics

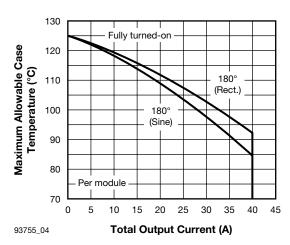


Fig. 4 - Current Ratings Characteristics

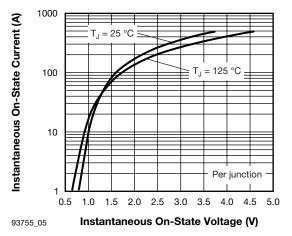


Fig. 5 - On-State Voltage Drop Characteristics



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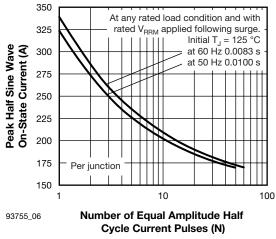


Fig. 6 - Maximum Non-Repetitive Surge Current

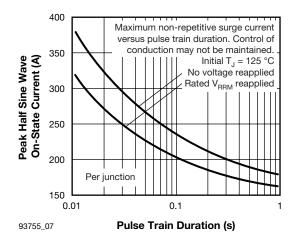


Fig. 7 - Maximum Non-Repetitive Surge Current

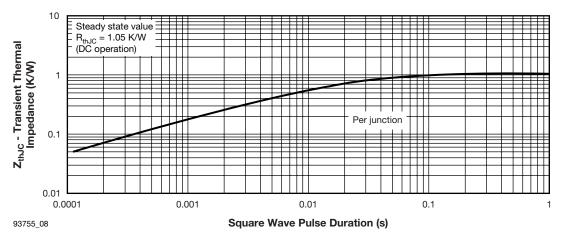


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

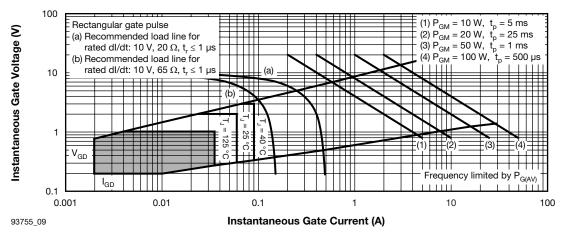


Fig. 9 - Gate Characteristics

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95335			



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